

Fast CMOS 3.3V 16-Bit Bidirectional Transceiver

Product Features

- Functionally compatible with FCT3, LVT, and 74 series 16245 families of products
- Tri-State outputs
- 5V Tolerant inputs and outputs
- 2.0V-3.6V V_{CC} supply operation
- Balanced sink and source output drives (24 mA)
- Low ground bounce outputs
- Supports live insertion
- ESD Protection exceeds 2000V, Human Body Model
200V, Machine Model
- Packages available:
 - 48-pin 240-mil wide plastic TSSOP (A)
 - 48-pin 300-mil wide plastic SSOP (V)

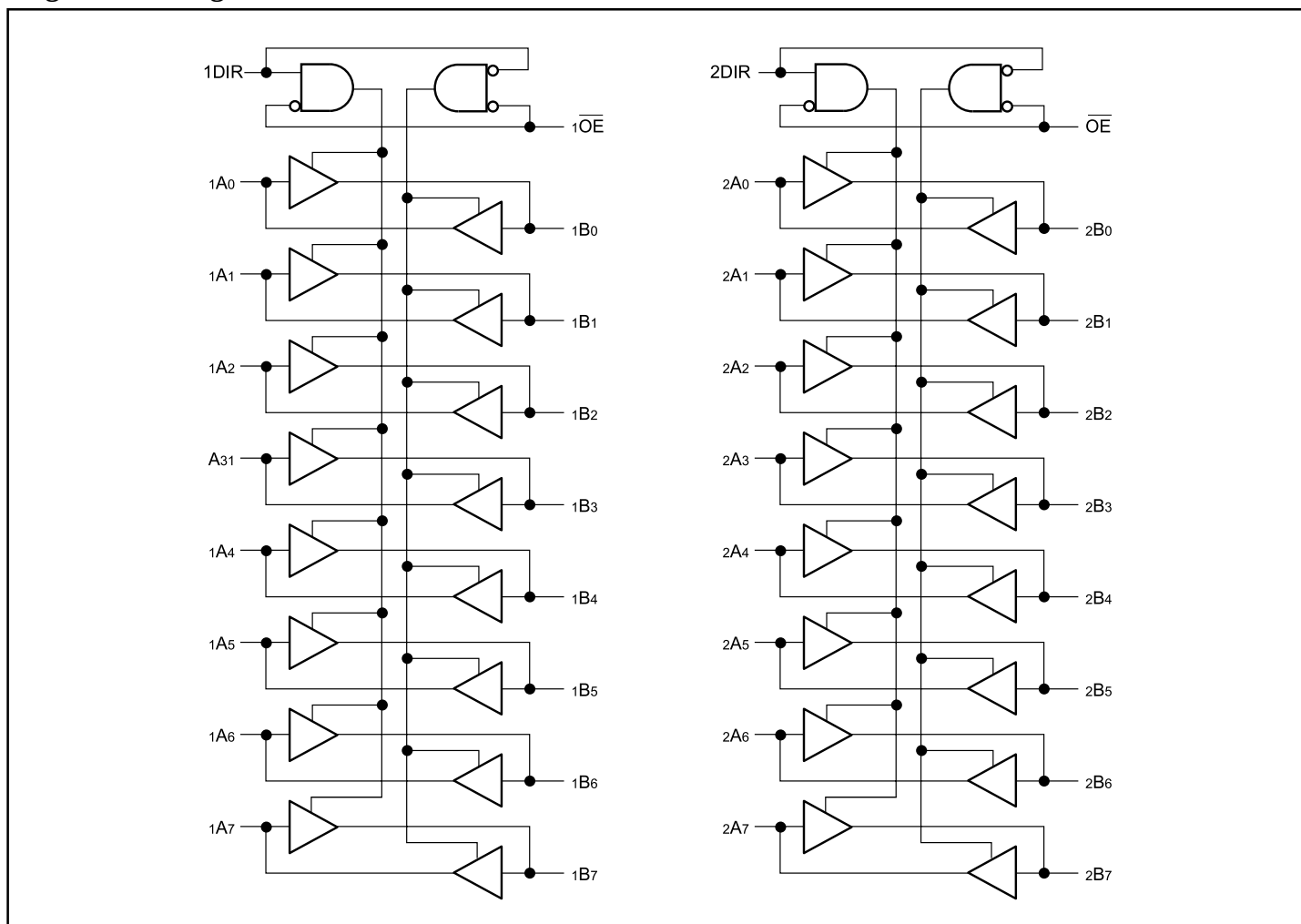
Product Description

Pericom Semiconductor's PI74LCX series of logic circuits are produced in the Company's advanced 0.6micron CMOS technology, achieving industry leading speed grades.

The PI74LCX16245 is a 16-bit bidirectional transceiver designed for asynchronous two-way communication between data buses. The direction control input pin (xDIR) determines the direction of data flow through the bidirectional transceiver. The Direction and Output Enable controls are designed to operate this device as either two independent 8-bit transceivers or one 16-bit transceiver. The output enable (OE) input, when HIGH, disables both A and B ports by placing them in HIGH Z condition.

The PI74LCX16245 can be driven from either 3.3V or 5.0V devices allowing this device to be used as a translator in a mixed 3.3/5.0V system.

Logic Block Diagram



Product Pin Description

Pin Name	Description
$\overline{xOE}$	3-State Output Enable Inputs (Active LOW)
xDIR	Direction Control Input
xAx	Side A Inputs or 3-State Inputs
xBx	Side B Outputs or 3-State Outputs
GND	Ground
VCC	Power

Truth Table⁽¹⁾

Inputs ⁽¹⁾		Outputs ⁽¹⁾
$\overline{xOE}$	xDIR	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	Z

Note:

1. H = High Voltage Level, X = Don't Care,
L = Low Voltage Level, Z = High Impedance

Product Pin Configuration

1DIR	1	48	$\overline{1OE}$
1B0	2	47	1A0
1B1	3	46	1A1
GND	4	45	GND
1B2	5	44	1A2
1B3	6	43	1A3
VCC	7	42	VCC
1B4	8	41	1A4
1B5	9	40	1A5
GND	10	39	GND
1B6	11	38	1A6
1B7	12	37	1A7
2B0	13	36	2A0
2B1	14	35	2A1
GND	15	34	GND
2B2	16	33	2A2
2B3	17	32	2A3
VCC	18	31	VCC
2B4	19	30	2A4
2B5	20	29	2A5
GND	21	28	GND
2B6	22	27	2A6
2B7	23	26	2A7
2DIR	24	25	$\overline{2OE}$

48-PIN
V48
A48

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	–40°C to +85°C
Supply Voltage to Ground Potential (Inputs & V _{CC} Only)	–0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only) ..	–0.5V to +7.0V
DC Input Voltage	–0.5V to +7.0V
DC Output Current	120 mA
Power Dissipation	1.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Parameter		Min.	Max.	Units
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V _I	Input Voltage		0	5.5	
V _O	Output Voltage	HIGH or LOW State	0	V _{CC}	
		Tri-State	0	5.5	
I _{OH} /I _{OL}	Output Current	V _{CC} = 3.0V-3.6V	—	±24	mA
		V _{CC} = 2.7V	—	±12	
T _A	Free-Air Operating Temperature		–40	+85	°C
Δt/ΔV	Input Edge Rate	V = 0.8V-2.0V, V _{CC} = 3.0V	0	10	ns/V

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 2.7\text{V}$ to 3.6V)

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Typ ⁽²⁾	Max.	Units
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level		2.0	—	—	V
V_{IL}	Input LOW Voltage	Guaranteed Logic LOW Level		—	—	0.8	
V_{OH}	Output HIGH Voltage	$V_{CC} = 2.7\text{-}3.6$	$I_{OH} = -0.1\text{mA}$	$V_{CC}-0.2$	—	—	
		$V_{CC} = 2.7$	$I_{OH} = -12\text{mA}$	2.2	—	—	
		$V_{CC} = 3.0$	$I_{OH} = -18\text{mA}$	2.4	—	—	
			$I_{OH} = -24\text{mA}$	2.2	—	—	
V_{OL}	Output LOW Voltage	$V_{CC} = 2.7\text{-}3.6$	$I_{OL} = 0.1\text{mA}$	—	—	0.2	
		$V_{CC} = 2.7$	$I_{OL} = 12\text{mA}$	—	—	0.4	
		$V_{CC} = 3.0$	$I_{OL} = 16\text{mA}$	—	—	0.4	
			$I_{OL} = 24\text{mA}$	—	—	0.55	
V_{IK}	Clamp Diode Voltage	$V_{CC} = \text{Min.}, I_{IN} = -18\text{mA}$		—	-0.7	-1.2	
I_I	Input Leakage Current	$0 \leq V_I \leq 5.5\text{V}$	$V_{CC} = 2.7\text{-}3.6$	—	—	± 5	μA
I_{OZ}	Tri-State Output Leakage	$0 \leq V_O \leq 5.5\text{V}$ $V_I = V_{IH}$ or V_{IL}	$V_{CC} = 2.7\text{-}3.6$	—	—	± 5	
I_{OFF}	Power Down Disable	$V_{CC} = 0\text{V}, V_{IN}$ or $V_{OUT} \leq 5.5\text{V}$		—	—	± 10	
I_{CC}	Quiescent Power Supply Current	$V_{CC} = \text{Max.}$	$V_{IN} = \text{GND}$ or V_{CC}	—	0.1	10	
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = \text{Max.}$	$V_{IN} = V_{CC} - 0.6\text{V}^{(3)}$	—	—	500	

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at $V_{CC} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient.
- Per TTL driven input; all other inputs at V_{CC} or GND .

Capacitance

Parameters	Description	Test Conditions	Typ.	Units
C_{IN}	Input Capacitance	$V_{CC} = \text{Open}, V_I = 0\text{V}$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3\text{V}, V_I = 0\text{V}$ or V_{CC}	8	
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3\text{V}, V_I = 0\text{V}$ or $V_{CC}, F = 10\text{MHz}$	20	

Switching Characteristics over Operating Range

Parameters	Description	Conditions	V _{CC} = 3.3V ± 0.3V		V _{CC} = 2.7V		Units
			Min.	Max.	Min.	Max.	
t _{PLH} t _{PHL}	Propagation Delay D _{XX} to O _{XX}	C _L = 50pF R _L = 500Ω	1.5	4.5	1.5	5.2	ns
t _{PZH} t _{PZL}	Output Enable time		1.5	6.5	1.5	7.2	
t _{PHZ} t _{PLZ}	Output Disable Time		1.5	6.4	1.5	6.9	
t _{SK(o)}	Output Skew ⁽¹⁾		—	1.0	—	—	

Notes:

1. Skew between any two outputs, of the same package, switching in the same direction.

Dynamic Switching Characteristics (T_A = +25°C)

Parameters	Description	Test Conditions ⁽¹⁾	Typ.	Units
V _{OLP}	Dynamic LOW Peak Voltage	V _{CC} = 3.3V, C _L = 50pF V _{IH} = 3.3V, V _{IL} = 0V	0.8	V
V _{OLV}	Dynamic LOW Valley Voltage	V _{CC} = 3.3V, C _L = 50pF V _{IH} = 3.3V, V _{IL} = 0V		

Note:

1. Measured with n–1 outputs switching from High-to-Low or Low-to-High. The remaining output is measured in the LOW state.